**MARKING** 



# TinyLogic UHS Inverter, Open Drain Output

### NC7SZ05

#### **Description**

The NC7SZ05 is a single inverter with open drain output stage from **onsemi**'s Ultra–High Speed series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad  $V_{CC}$  operating range. The device is specified to operate over the 1.65 V to 5.5 V  $V_{CC}$  operating range. The inputs and output are high–impedance when  $V_{CC}$  is 0 V. Inputs tolerate voltages up to 5.5 V, independent of  $V_{CC}$  when in the high–impedance state.

#### **Features**

- Ultra-High Speed: tpD =1.9 ns (Typical) into 50 pF at 5 V V<sub>CC</sub>
- Open Drain Output for OR Tied Applications
- High Output Drive: ±24 mA at 3 V V<sub>CC</sub>
- Broad V<sub>CC</sub> Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX Operated at 3.3 V V<sub>CC</sub>
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry Implemented
- Ultra-Small MicroPak<sup>TM</sup> Packages
- Space–Saving SOT23–5, SC–74A and SC–88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol

1

### **DIAGRAMS** C6KK SIP6 1.45x1.0 CASE 127EB XYZ **UDFN6** C6KK 1.0X1.0, 0.35P XYZ CASE 517DP SC-74A 7Z05 M■ CASE 318BQ SOT23-5 7Z05 M CASE 527AH Z05 M= SC-88A CASE 419A-02

C6, 7Z05, Z05 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
XX = Device Code

M = Date Code\*
■ Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

#### **Pin Configurations**

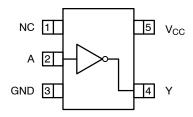


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

#### NC 1 6 V<sub>CC</sub> A 2 5 NC GND 3 4 Y

Figure 3. MicroPak (Top Through View)

#### **PIN DEFINITIONS**

Pin # SOT23-5 / SC-88A / SC74-A	Pin # MicroPak	Name	Description
1	1, 5	NC	No Connect
2	2	Α	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V <sub>CC</sub>	Supply Voltage

#### **FUNCTION TABLE**

Inputs	Output
Α	Υ
L	*H
Н	L

H = HIGH Logic Level L = LOW Logic Level \*H = High Impedance Output State, Open Drain

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Param	eter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5	6.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-50	mA
l <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-50	mA
I <sub>OUT</sub>	DC Output Current	•	-	±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	-	±50	mA	
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
$T_J$	Junction Temperature Under Bias		-	+150	°C
$T_L$	Junction Lead Temperature (Solde	ering, 10 Seconds)	-	+260	°C
$P_{D}$	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JES	D22-A114	-	4000	V
	Charge Device Model, JEDEC: JE	SD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.50	5.50	
V <sub>IN</sub>	Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Times	V <sub>CC</sub> at 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V <sub>CC</sub> at 3.3 V ±0.3 V	0	10	
		V <sub>CC</sub> at 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

#### DC ELECTICAL CHARACTERISTICS

				T,	λ = +25°	·C	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage	1.65 to 1.95		0.65 V <sub>CC</sub>	-	-	0.65 V <sub>CC</sub>	-	V
		2.30 to 5.50		0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
V <sub>IL</sub>	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
		2.30 to 5.50		-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	
I <sub>LKG</sub>	HIGH Level Output Leakage Current	1.65 to 5.50	$V_{IN} = V_{IH}$ or $V_{IL}$ , $V_{OUT} = V_{CC}$ or GND	-	-	±5	-	±10	μΑ
V <sub>OL</sub>	LOW Level Output Voltage	1.65	$V_{IN} = V_{IH} \text{ or } V_{IL},$	-	0.00	0.10	-	0.10	٧
		1.80	I <sub>OL</sub> = 100 μA	_	0.00	0.10	-	0.10	
		2.30		_	0.00	0.10	-	0.10	
		3.00		_	0.00	0.10	-	0.10	
		4.50		_	0.00	0.10	-	0.10	
		1.65	I <sub>OL</sub> = 4 mA	-	0.80	0.24	-	0.24	
		2.30	I <sub>OL</sub> = 8 mA	-	0.10	0.30	-	0.30	
		3.00	I <sub>OL</sub> = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I <sub>OL</sub> = 24 mA	-	0.22	0.55	-	0.55	
		4.50	I <sub>OL</sub> = 32 mA	-	0.22	0.55	-	0.55	
I <sub>IN</sub>	Input Leakage Current	1.65 to 5.5	$0 \leq V_{IN} \leq 5.5 \; V$	-	-	±1	-	±10	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	0	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	-	-	1	_	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	1.65 to 5.50	V <sub>IN</sub> = 5.5 V, GND	-	-	2	-	20	μΑ

#### **AC ELECTRICAL CHARACTERISTICS**

				$T_A = +25^{\circ}C$ $T_A = -40^{\circ}$		T <sub>A</sub> = -40	to +85°C		
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay	1.65	C <sub>L</sub> = 50 pF,	-	5.5	12.9	-	13.4	ns
	(Figure 4, 5)	1.80	RU = 500 $\Omega$ , RD = 500 $\Omega$ ,	-	4.6	10.5	-	11.0	
		2.50 ±0.20	$V_{IN} = 2 \cdot V_{CC}$	-	3.0	7.0	-	7.5	
		3.30 ±0.30		-	2.4	5.0	-	5.2	
		5.00 ±0.50		-	1.9	4.3	-	4.5	
t <sub>PLZ</sub>		1.65	C <sub>L</sub> = 50 pF,	-	5.0	12.9	-	13.4	ns
		4 00	RU = 500 $\Omega$ , RD = 500 $\Omega$ ,	-	4.1	10.5	-	11.0	
		2.50 ±0.20	$V_{IN} = 2 \cdot V_{CC}$	-	2.5	7.0	-	7.5	
		3.30 ±0.30		-	2.1	5.0	-	5.2	
		5.00 ±0.50		-	1.2	4.3	-	4.5	
C <sub>IN</sub>	Input Capacitance	0.00		-	4.0	-	-	-	pF
C <sub>OUT</sub>	Output Capacitance	0.00		-	6.0	-	-	_	pF
C <sub>PD</sub>	C <sub>PD</sub> Power Dissipation Capacitance (Note 2) (Figure 6)	3.30		-	3.6	-	-	_	pF
		5.00		-	6.5	_	-	-	

<sup>2.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression: I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).



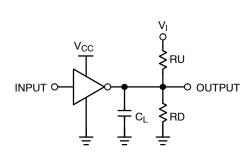


Figure 4. AC Test Circuit

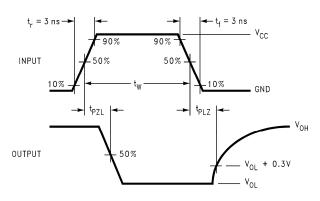
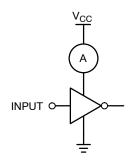


Figure 5. AC Waveforms



NOTE:

3. Input = AC Waveform;  $t_r = t_f = 1.8 \text{ ns}$ ; PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. Test Circuit

#### **DEVICE ORDERING INFORMATION**

Device	Top Mark	Packages	Shipping <sup>†</sup>
NC7SZ05M5X	7Z05	5-Lead SC-74A, 1.6mm	3000 / Tape & Reel
NC7SZ05P5X	Z05	5-Lead SC70, EIAJ SC-88A, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ05L6X	C6	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ05FHX	C6	6-Lead, MicroPak2, 1 x 1 mm Body, 0.35 mm Pitch	5000 / Tape & Reel

#### **DISCONTINUED** (Note 4)

NC7SZ05M5X-L22090	7Z05	SOT23-5	3000 / Tape & Reel
NC7SZ05P5X-L22057	Z05	5-Lead SC70, EIAJ SC-88A, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ05L6X-L22175	C6	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ05FHX-L22175	C6	6-Lead, MicroPak2, 1 x 1 mm Body, 0.35 mm Pitch	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak is trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.

<sup>4.</sup> **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.



**ISSUE O DATE 31 AUG 2016** 2X 0.05 C 1.45 В 2X (1) $\bigcirc$  0.05 C (0.49)(0.254)1.00 5X \ (0.75)(0.52)TOP VIEW Α 1X <u>1</u> PIN 1 IDENTIFIER /5\ 0.50±0.05 (0.30)6X PIN 1 0.05 RECOMMENED 0.00 LAND PATTERN 0.05 C - 0.35±0.05 С 1.45±0.05 -0.20±0.05 6X DETAIL A 1.0 0.10M|C|B|A

0.05(M)

0.30±0.05 5X

0.35±0.05 5X

(0.125)

4X

**SIP6 1.45X1.0** CASE 127EB

NOTES:

1.00±0.05

(0.050)

6X

1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD

0.5

- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009

**BOTTOM VIEW** 

- 4.PIN ONE IDENTIFIER IS 2X LENGTH OF ANY
  - OTHER LINE IN THE MARK CODE LAYOUT.

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DESCRIPTION:	SIP6 1.45X1.0		PAGE 1 OF 1		

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0.40±0.05

**PIN 1 TERMINAL** 

**DETAIL** A

0.075 X 45°

CHAMFER

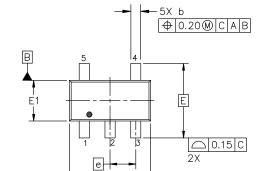


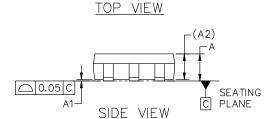
A

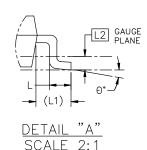


#### SC-74A-5 3.00x1.50x0.95, 0.95P CASE 318BQ ISSUE C

**DATE 26 FEB 2024** 







## GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

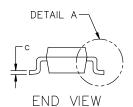
= Pb-Free Package

(Note: Microdot may be in either location)

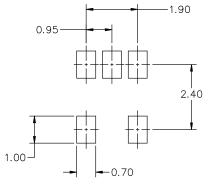
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.



DIM	М	ILLIMETER	RS	
DIIVI	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
A1	0.01	0.18	0.10	
A2	(	0.95 REF		
b	0.25	0.37	0.50	
С	0.10	0.18	0.26	
D	2.85	3.00	3.15	
Е	:	2.75 BSC	;	
E1	1.35	1.50	1.65	
е	(	0.95 BSC	)	
L	0.20	0.40	0.60	
L1	0.62 REF.			
L2	0.25 BSC			
Θ	0,	5*	10°	



#### RECOMMENDED MOUNTING FOOTPRINT\*

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Document Ri- Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION	SC-74A-5 3.00x1.50x0.95	0.95P	PAGE 1 OF 1

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#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

**DATE 11 APR 2023** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MILLIMETERS			
ואונת	MIN.	N□M.	MAX.	
А	0.80	0.95	1.10	
A1			0.10	
A3	0,20 REF			
b	0.10	0.20	0.30	
C	0.10		0.25	
D	1.80	2.00	2,20	
Е	2.00	2.10	2.20	
E1	1.15	1.25	1.35	
е	0,65 BSC			
L	0.10	0.15	0.30	

- 419A-01 DBSDLETE, NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS,

	L <del> </del> <del> </del>		
<u> </u>	0.50	5	

5X b

◆ 0.2 M B M

#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

#### **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

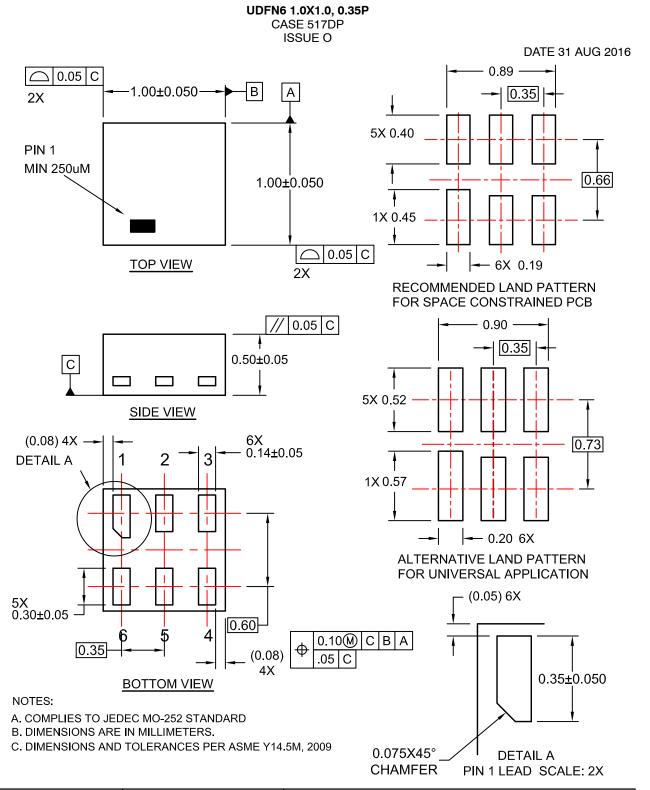
DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)		PAGE 1 OF 1	

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5. COLLECTOR 2/BASE 1





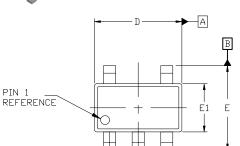


DOCUMENT NUMBER:	98AON13593G	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6 1.0X1.0, 0.35P		PAGE 1 OF 1

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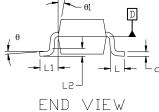






### 

TOP VIEW



### GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code
M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

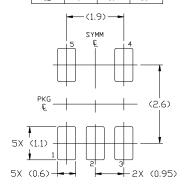
#### SOT-23, 5 Lead CASE 527AH ISSUE A

**DATE 09 JUN 2021** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS.
   MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED O. 25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- 5. DIMENSION '6' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE '6' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.90	_	1.45	
A1	0.00	_	0.15	
A2	0.90	1.15	1.30	
b	0.30	_	0.50	
C	0.08	_	0.22	
D	2.90 BSC			
Ε	2.80 BSC			
E1	1.60 BSC			
е	0.95 BSC			
L	0.30	0.45	0.60	
L1	0.60 REF			
L2	0.25 REF			
θ	0°	4°	8°	
θ1	0°	10°	15°	
θ2	0°	10°	15°	



### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDL DERRM/D.

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